# NSN 5962-01-367-1270

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View Online at https://aerobasegroup.com/nsn/5962-01-367-1270

Body Length:
1.280 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Eo lorops
Features Provided:
Hermetically sealed and burn in and monolithic and ultraviolet erasable and positive outputs
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
14 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-9 mil-m-38510
Current Rating Per Characteristic:
100.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

# **Capitance Rating Per Characteristic:**

6.00 input picofarads and 8.00 output picofarads

# **Time Rating Per Chacteristic:**

45.00 nanoseconds access

# **Memory Device Type:**

Eprom

# **Special Features:**

Esd. Programmed from p/n 67268 5962-8752901la

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Terminal Type A	nd Quantity:
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24 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0